

HT12M 2¹² Decoder Doorbell

Features

- Operating voltage: 2.4V~5.0V
- Built-in AMP
- · 2-channel dual tone generator
- · One pin oscillator

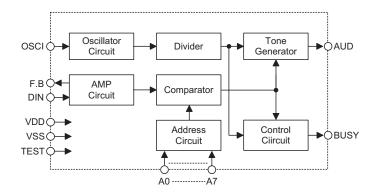
- · Current type D/A output
- Tone optional: Ding-Dong/Westminster's tunes
- Pair with HT12E encoder
- 16-pin DIP package

General Description

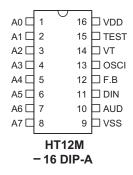
The main application area for the HT12M device is for remote control doorbells working together with HT12E. Containing all the functions of the Holtek HT12D decoder and with an added amplifier and tone generator, the device eliminates the need for customers to incorporate an external op-amp and tone generator IC within their product applications, in the process significantly reducing overall product costs.

In addition to being fully compatible with the HT12D circuitry, the device includes the following features; internal Inverting AMP with can also operate as standard independent inverter, internal 2 channel tone generator and current type audio output.

Block Diagram

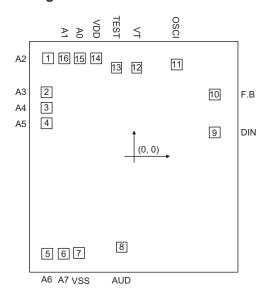


Pin Assignment





Pad Assignment



Pad Coordinates

Unit: µm

Pad No.	Х	Υ
1	-610.00	701.90
2	-622.00	461.60
3	-622.00	350.60
4	-622.00	239.70
5	-616.00	-695.20
6	-502.00	-695.20
7	-388.50	-687.70
8	-87.95	-647.80
9	575.80	172.40
10	575.80	444.20
11	308.30	660.40
12	22.10	635.90
13	-122.40	638.40
14	-270.40	701.90
15	-384.50	701.90
16	-495.50	701.90

Chip size: 1530 \times 1690 μm

Pin Description

Pin No.	Pin Name	I/O	Internal Connection	Description
1~8	A0~A7	I	NMOS Open Drain	Address pin
9	VSS		_	Negative power supply, ground
10	AUD	0	PMOS Open Drain	Audio out
11	DIN	_	COMS IN	Serial data input
12	F.B	0	CMOS	Amp feed back
13	OSCI	I	_	Oscillator input pin
14	VT	0	CMOS	Busy, data valid
15	TEST	Ι	CMOS IN	Test pin
16	VDD		— Positive power supply	

Absolute Maximum Ratings

Supply Voltage	$V_{\rm SS}$ =0.3V to $V_{\rm SS}$ +5.5V	Storage Temperature	50°C to 125°C
Input Voltage	Vss-0.3V to Vnn+0.3V	Operating Temperature	−25°C to 70°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

^{*} The IC substrate should be connected to VSS in the PCB layout artwork.

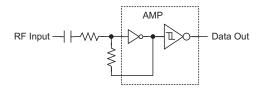


D.C. Characteristics

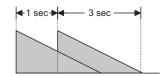
Cumbal	Davamatar		Test Conditions		_		11
Symbol	Parameter	V_{DD}	Conditions	Min.	Тур.	Max.	Unit
V_{DD}	Operating Voltage	_	_	2.4	_	5	V
		5V	OSC stop amp Off	_	0.1	1	μА
I _{STB}	Standby Current	5V	OSC stop amp On	_	10	20	μА
I _{DD}	Operating Current	5V	No load f _{OSC} =150kHz	_	1.5	2	mA
I _{AUD}	AUD Output Current	5V	Transistor B load	3	5	_	mA
	VT Output Source Current		V _{OH} =4.5V	-2	-3	_	mA
VT Output Sink Current		5V	V _{OL} =0.5V	2	3	_	mA
V _{IH}	High Input Voltage	5V	_	3.5	_	5	V
V _{IL}	Low Input Voltage	5V	_	0	_	1	V
fosc	Oscillator Frequency	5V	R _{OSC} =820kΩ	_	190	_	kHz

Functional Description

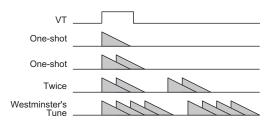
Built-in Inverter Amp

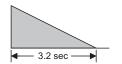


Single tone has 4 second total length, dual tone has 1 second total length.









The Ding-Dong sound: is determined by the D8 \sim D11 pins on the HT12E. While the Re-trigger/Non-trigger function is determined by the D11 pin on the HT12E.

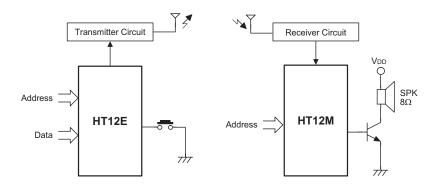
	D11	D10	D9	D8	Sound	Notes
1		0	0	0	Mi	1
2		0	0	1	Mi Do	2
3		0	1	0	Mi Do — Mi Do	Repeat
4		0	1	1	Mi/Do	Single tone
5		1	0	0	Mi Do Re Sol — Sol Re Mi Do	Westminster's tune
6		1	0	1	Mi/Do Do/Sol	Double tone
7		1	1	0	Sol Re Mi Do	4
8		1	1	1	Mi/Do Do/Sol — Mi/Do Do/Sol	Dual Tone-repeat

Note: Section time: $0.8sec \times 2 = 1.6sec$

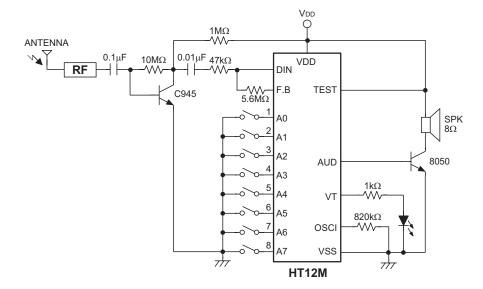


Application Circuit

HT12E/HT12M Pairing Application Circuit

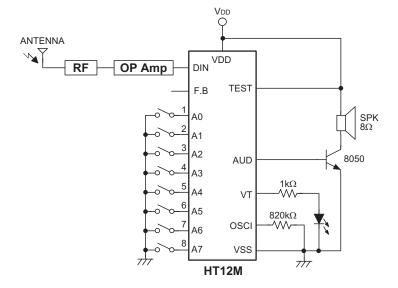


Using Internal OP Amplifier Circuit

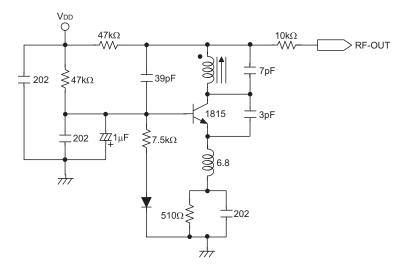




Using External OP Amplifier Circuit



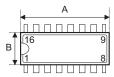
Typical RF-Receiver Circuit

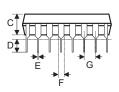




Package Information

16-pin DIP (300mil) Outline Dimensions







Cumhal	Dimensions in mil				
Symbol	Min.	Nom.	Max.		
А	745	_	775		
В	240	_	260		
С	125	_	135		
D	125	_	145		
E	16	_	20		
F	50	_	70		
G	_	100	_		
Н	295	_	315		
I	335	_	375		
α	0°	_	15°		



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